## **QUAD OPERATIONAL AMPLIFIERS**

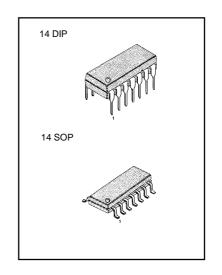
The KA224 series consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide voltage range.

Operation from split power supplies is also possible so long as the difference between the two supplies is 3 volts to 32 volts.

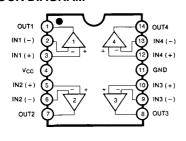
Application areas include transducer amplifier, DC gain blocks and all the conventional OP amp circuits which now can be easily implemented in single power supply systems.

## **FEATURES**

- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range: KA224/A, KA324/A: 3V 32V (or  $\pm$  1.5 ~ 15V) KA2902: 3V~26V (or  $\pm$  1.5V ~ 13V)
- Input common-mode voltage range includes ground
- $\bullet~$  Large output voltage swing: 0V DC to  $V_{\text{CC}}$  -1.5V DC
- Power drain suitable for battery operation.



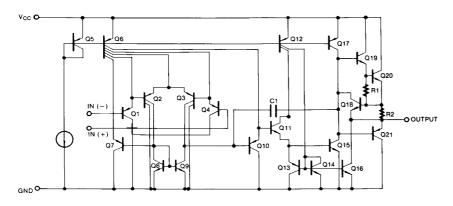
## **BLOCK DIAGRAM**



## **ORDERING INFORMATION**

Device	Package	Operating Temperature
KA324	14 DIP	
KA324A	14 DIF	0 ~ + 70℃
KA324D	14 SOP	0~+700
KA324AD	14 30F	
KA224	14 DIP	
KA224A	14 011	-25 ~ +85 ℃
KA224D	14 SOP	25 - 100 0
KA224AD	14 30F	
KA2902	14 DIP	-40 ~ + 85℃
KA2902D	14 SOP	-40 ~ + 00 C

# SCHEMATIC DIAGRAM (One Section Only)





# **ABSOLUTE MAXIMUM RATINGS**

Characteristic	Symbol	KA224/KA224A	KA324/KA324A	KA2902	Unit
Power Supply Voltage	V <sub>CC</sub>	± 18 or 32	± 18 or 32	± 13 or 26	V
Differential Input Voltage	$V_{I(DIFF)}$	32	32	26	V
Input Voltage	Vı	-0.3 to + 32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND		Continuous	Continuous	Continuous	
V <sub>CC</sub> ≤ 15V T <sub>A</sub> =25 °C (One Amp)		Continuous	Continuous	Continuous	
Power Dissipation	$P_D$	570	570	570	mW
Operating Temperature Range	$T_{OPR}$	-25 ~ +85	0 ~ + 70	-40 ~ + 85	$^{\circ}$
Storage Temperature Range	T <sub>STG</sub>	-65 ~ + 150	-65 ~ + 150	-65 ~ + 150	${\mathbb C}$

# **ELECTRICAL CHARACTERISTICS**

	Sball			KA224			KA324			K	A290		
Characteristic	Symbol	Test Conditions		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V <sub>IO</sub>	$V_{CM} = 0V \text{ to } V_{CC} = 1.5V$ $V_{O(P)} = 1.4V, R_S = 0\Omega$			1.5	5.0		1.5	7.0		1.5	7.0	mV
Input Offset Current	I <sub>IO</sub>				2.0	30		3.0	50		3.0	50	nA
Input Bias Current	I <sub>BIAS</sub>				40	150		40	250		40	250	nA
Input Common-Mode Voltage Range	$V_{I(R)}$	$V_{CC} = 30$ \ $(V_{CC} = 26$ V for K		0		V <sub>CC</sub> -1.5	0	V <sub>CC</sub> -1.5		0		V <sub>CC</sub> -1.5	V
		$R_L = ,V_{CC} = 30V$	(all Amps)		1.0	3		1.0	3		1.0	3	mA
Supply Current	Icc	$R_L = ,V_{CC} = 5V ($ $(V_{CC} = 26V \text{ for } K)$			0.7	1.2		0.7	1.2		0.7	1.2	mA
Large Signal Voltage Gain	G∨	$V_{CC} = 15V, R_L \ge 2K\Omega$ $V_{O(P)} = 1V \text{ to } 11V$		50	100		25	100			100		V/mV
	.,	V <sub>CC</sub> = 30V	$R_L = 2K\Omega$	26			26			22			V
Output Voltage Swing	V <sub>O(H)</sub>	V <sub>CC</sub> =26V for 2902	$R_L = 10K\Omega$	27	28		27	28		23	24		V
	$V_{O(L)}$	$V_{CC} = 5V, R_L \ge 10K\Omega$			5	20		5	20		5	100	mV
Common-Mode Rejection Ratio	CMRR			70	85		65	75		50	75		dB
Power Supply Rejection Ratio	PSRR			65	100		65	100		50	100		dB
Channel Separation	CS	f = 1KHz to 20	)KHz		120			120			120		dB
Short Circuit to GND	I <sub>SC</sub>				40	60		40	60		40	60	mA
	I <sub>SOURCE</sub>	$V_{I(+)} = 1V, V_{I(-)}$ $V_{CC} = 15V, V_{O(F)}$		20	40		20	40		20	40		mA
Output Current		$V_{I(+)} = 0V, V_{I(-)}$ $V_{CC} = 15V, V_{O(F)}$		10	13		10	13		10	13		mA
	I <sub>SINK</sub>	$V_{I(+)} = 0V, V_{I(-)}$ $V_{CC} = 15V, V_{O(R)} =$	= 1V	12	45		12	45					μА
Differential Input Voltage	$V_{I(DIFF)}$					V <sub>cc</sub>			V <sub>cc</sub>			V <sub>cc</sub>	V



# **ELECTRICAL CHARACTERISTICS**

 $(V_{CC}=5.0V,\,V_{EE}=GND,\,$  unless otherwise specified) The following specification apply over the range of -25  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C for the KA224; and the 0  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C for the KA324; and the - 40  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C for the KA2902

Characteristic	Cumbal	Symbol Test Conditions			KA224			KA32	4	K	Unit		
Characteristic	Syllibol	rest cont	aitions	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Onit
Input Offset Voltage	V <sub>IO</sub>	$V_{ICM} = 0V \text{ to } V_{CC} = V_{O(P)} = 1.4V, R_S = 0$				7.0			9.0			10.0	mV
Input Offset Voltage Drift	Δ V <sub>IO</sub> /Δ Τ				7.0			7.0			7.0		μ <b>V/</b> ℃
Input Offset Current	I <sub>IO</sub>					100			150			200	nΑ
Input Offset Current Drift	Δ Ι <sub>ΙΟ</sub> /Δ Τ				10			10			10		pA/℃
Input Bias Current	I <sub>BIAS</sub>					300			500			500	nA
Input Common-Mode Voltage Range	V <sub>IC(R)</sub>	$V_{CC} = 30V$ $(V_{CC} = 26V \text{ for KA2})$	902)	0		V <sub>CC</sub> -2.0	0		V <sub>CC</sub> -2.0	0		V <sub>CC</sub> -2.0	V
Large Signal Voltage Gain	G <sub>V</sub>	$V_{CC} = 15V, R_L \ge 2.0$ $V_{O(P)} = 1V \text{ to } 11V$	OKΩ	25			15			15			V/mV
	.,,	$V_{CC} = 30V$	$R_L = 2K\Omega$	26			26			22			V
Output Voltage Swing	V <sub>O(H)</sub>	$V_{CC} = 26V \text{ for } 2902$	$R_L = 10K\Omega$	27	28		27	28		23	24		V
	$V_{O(L)}$	$V_{CC} = 5V, R_L \ge 10K$	Ω		5	20		5	20		5	100	mV
Output Current	I <sub>SOURCE</sub>	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2$		10	20		10	20		10	20		mA
Output Current	I <sub>SINK</sub>	$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(P)} =$		10	13		5	8		5	8		mA
Differential Input Voltage	V <sub>I(DIFS)</sub>					Vcc			V <sub>CC</sub>			V <sub>CC</sub>	V



# **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol Test Conditions		K	A224	Α				
Characteristic	Symbol			Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V <sub>IO</sub>	$V_{CM} = 0V \text{ to } V_{CC} = 1.5V$ $V_{O(P)} = 1.4V, R_S = 0$		1.0	3.0		1.5	3.0	mV
Input Offset Current	I <sub>IO</sub>			2	15		3.0	30	nA
Input Bias Current	I <sub>BIAS</sub>			40	80		40	100	nA
Input Common-Mode Voltage Range	V <sub>I(R)</sub>	V <sub>CC</sub> = 30V	0		V <sub>CC</sub> -1.5	0		V <sub>CC</sub> -1.5	V
Supply Current (All Amps)	Icc	$V_{CC} = 30V$		1.5	3		1.5	3	mA
Supply Current (All Allips)	100	$V_{CC} = 5V$		0.7	1.2		0.7	1.2	mA
Large Signal Voltage Gain	G <sub>V</sub>	$V_{CC} = 15V, R_L \ge 2K\Omega$ $V_{O(P)} = 1V \text{ to } 11V$	50	100		25	100		V/mV
	V <sub>O(H)</sub>	$V_{CC} = 30V$ $R_L = 2K\Omega$	26			26			V
Output Voltage Swing		$V_{CC} = 26V \text{ for } 2902  R_L = 10K\Omega$	27	28		27	28		V
	V <sub>O(L)</sub>	V <sub>CC</sub> = 5V, R <sub>L</sub> ≥ 10KΩ		5	20		5	20	mV
Common-Mode Rejection Ratio	CMRR		70	85		65	85		dB
Power Supply Rejection Ratio	PSRR		65	100		65	100		dB
Channel Separation	CS	f = 1KHz to 20KHz		120			120		dB
Short Circuit to GND	I <sub>sc</sub>			40	60		40	60	mA
	I <sub>SOURCE</sub>	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V$	20	40		20	40		mA
Output Current	1	$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(P)} = 2V$	10	20		10	20		mA
	I <sub>SINK</sub>	$V_{I(+)} = 0v, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(P)} = 200mV$	12	50		12	50		μА
Differential Input Voltage	V <sub>I(DIFF)</sub>				$V_{CC}$			$V_{CC}$	V



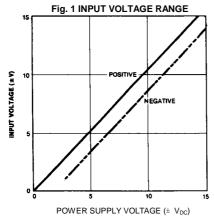
# **ELECTRICAL CHARACTERISTICS**

 $(V_{CC}$  = 5.0V,  $V_{EE}$  = GND, unless otherwise specified) The following specification apply over the range of -25  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C for the KA224A; and the  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C  $^{\circ}$ C for the KA324A

Characteristic	0	ool Test Conditions		KA224		224A		KA324		
Characteristic	Symbol			Min	Тур	Max	Min	Тур	Max	Unit
Input Offset Voltage	V <sub>IO</sub>	-	$V_{CM} = 0V \text{ to } V_{CC} = 1.5V$ $V_{O(P)} = 1.4V, R_S = 0\Omega$			4.0			5.0	mV
Input Offset Voltage Drift	Δ V <sub>IO</sub> /Δ T				7.0	20		7.0	30	μ <b>V</b> /℃
Input Offset Current	I <sub>IO</sub>					30			75	nA
Input Offset Current Drift	Δ Ιιο/Δ Τ				10	200		10	300	pA/℃
Input Bias Current	I <sub>BIAS</sub>				40	100		40	200	nA
Input Common-Mode Voltage Range	V <sub>I(R)</sub>	V <sub>CC</sub> = 30V		0		V <sub>CC</sub> -2.0	0		V <sub>CC</sub> -2.0	V
Large Signal Voltage Gain	G <sub>V</sub>	V <sub>CC</sub> = 15V, I	R <sub>L</sub> ≥ 2.0KΩ	25			15			V/mV
Output Voltage Swing	V <sub>O(P-P)</sub>	V <sub>CC</sub> = 30V	$R_L = 2K\Omega$ $R_L = 10K\Omega$	26 27	28		26 27	28		٧
o a p an a samuga o a annig	10(14)	V <sub>CC</sub> = 5V, F			5	20		5	20	mA
Output Output	I <sub>SOURCE</sub>	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V$		10	20		10	20		mA
Output Current	I <sub>SINK</sub>	$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V$		5	8		5	8		mA
Differential Input Voltage	V <sub>I(DIFF)</sub>					$V_{CC}$			$V_{CC}$	V



# TYPICAL PERFORMANCE CHARACTERISTICS



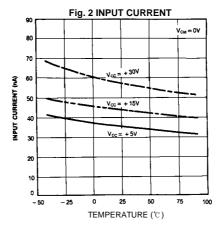


Fig. 3 SUPPLY CURRENT

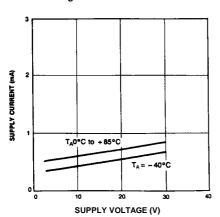


Fig. 4 VOLTAGE GAIN

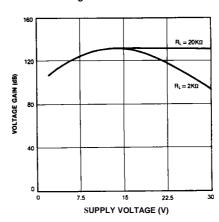


Fig. 5 OPEN LOOP FREGUENCY RESPONSE

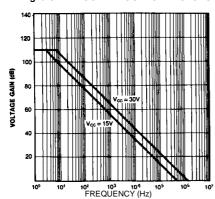
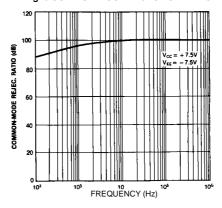


Fig. 6 COMMON.MOOE REJECTION RATIO





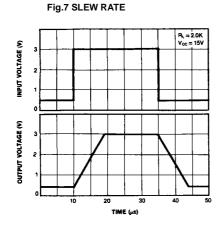


Fig. 8 VOLTAGE FOLLOWER PULSE RESPONSE (SMALL SIGNAL)

TA = 25°C
Vcc = +30V

NPUT
OUTPUT

OUTPUT

350
275
0 1 2 3 4 5 6 7 8 9

Fig. 9 LARGE SIGNAL FREQUECY RESPONSE

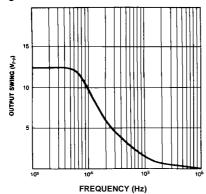


Fig. 10 OUTPUT CHARACTERISTICS CURRENT SOURCING

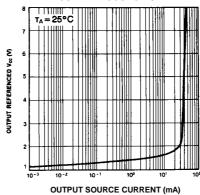


Fig. 11 OUTPUT CHARACTERISTICS CURRENT SINKING

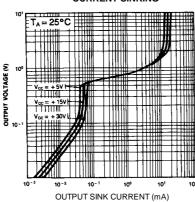
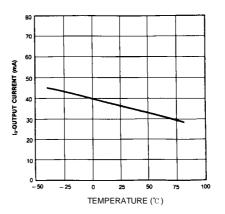


Fig. 12 CURRENT LIMITING





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